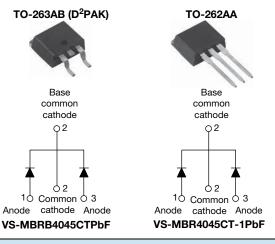
VS-MBRB4045CTPbF, VS-MBR4045CT-1PbF

Vishay Semiconductors

epoxy

High Performance Schottky Rectifier, 2 x 20 A



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| PRODUCT SUMMARY | |
|----------------------------------|---|
| Package | TO-263AB (D ² PAK), TO-262AA |
| I _{F(AV)} | 40 A |
| V _R | 45 V |
| V _F at I _F | 0.58 V |
| I _{RM} max. | 95 mA at 125 °C |
| T _J max. | 150 °C |
| Diode variation | Common cathode |
| E _{AS} | 20 mJ |

FEATURES

High

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation

purity,

• Center tap TO-220, D²PAK and TO-262 packages



encapsulation for enhanced mechanical FREE strength and moisture resistance
Guard ring for enhanced ruggedness and long term

high temperature

- reliability • Meets MSL level 1, per J-STD-020, LF maximum peak
- of 260 °C
- AEC-Q101 qualified
 Material categorization: for definition
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND | CHARACTERISTICS | | |
|--------------------------|--|-------------|-------|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS |
| I _{F(AV)} | Rectangular waveform (per device) | 40 | ٨ |
| I _{FRM} | T _C = 118 °C (per leg) | 40 | A |
| V _{RRM} | | 45 | V |
| I _{FSM} | t _p = 5 μs sine | 900 | А |
| V _F | 20 A _{pk} , T _J = 125 °C | 0.58 | V |
| TJ | Range | -65 to +150 | °C |

| VOLTAGE RATINGS | | | |
|--------------------------------------|------------------|---------------------------------------|-------|
| PARAMETER | SYMBOL | VS-MBRB4045CTPbF VS-MBR4045CT-1PbF | UNITS |
| Maximum DC reverse voltage | V _R | 45 | V |
| Maximum working peak reverse voltage | V _{RWM} | 45 | v |

| ABSOLUTE MAXIMUM RATI | NGS | | | | |
|---|--------------------|---|---|--------|-------|
| PARAMETER | SYMBOL | TEST COND | TIONS | VALUES | UNITS |
| Maximum average per leg | | T _C = 118 °C, rated V _B | | 20 | |
| forward current per device | I _{F(AV)} | $T_{\rm C} = 116$ C, rated $V_{\rm R}$ | | 40 | |
| Peak repetitive forward current per leg | I _{FRM} | Rated V_R , square wave, 20 kHz, | T _C = 118 °C | 40 | А |
| Maximum peak one cycle non-repetitive | 1 | 5 µs sine or 3 µs rect. pulse | Following any rated load condition and with rated | 900 | |
| peak surge current per leg | I _{FSM} | 10 ms sine or 6 ms rect. pulse | V _{RRM} applied | 210 | |
| Non-repetitive avalanche energy per leg | E _{AS} | T _J = 25 °C, I _{AS} = 3 A, L = 4.4 mH | 1 | 20 | mJ |
| Repetitive avalanche current per leg | I _{AR} | Current decaying linearly to zero Frequency limited by T _J maximu | | 3 | А |

Revision: 15-Jul-14

Document Number: 94311

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| ELECTRICAL SPECIFICATIONS | | | | | |
|--|--------------------------------|-----------------------------------|-----------------------------|--------|-------|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | VALUES | UNITS |
| | | 20 A | T, = 25 °C | 0.60 | |
| | V _{FM} ⁽¹⁾ | 40 A | 1j=25 C | 0.78 | V |
| Maximum forward voltage drop | V FM (*) | 20 A | T 105 %O | 0.58 | |
| | | 40 A | T _J = 125 °C | 0.75 | |
| | | T _J = 25 °C | | 1 | |
| Maximum instantaneous reverse current | I _{RM} ⁽¹⁾ | T _J = 100 °C | Rated DC voltage | 50 | mA |
| | | T _J = 125 °C | | 95 | |
| Maximum junction capacitance | C _T | $V_R = 5 V_{DC}$ (test signal ran | ge 100 kHz to 1 MHz), 25 °C | 900 | pF |
| Typical series inductance | L _S | Measured from top of terr | minal to mounting plane | 8.0 | nH |
| Maximum voltage rate of change | dV/dt | Rated V _R | | 10 000 | V/µs |

Note

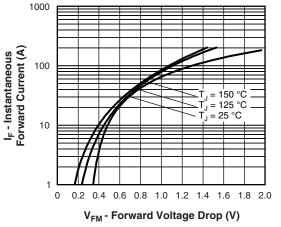
 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

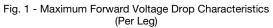
| THERMAL - MECHANICAL SPECIFICATIONS | | | | |
|--|-------------------|--|-------------|------------|
| PARAMETER | SYMBOL | TEST CONDITIONS VAL | | UNITS |
| Maximum junction temperature range | TJ | | -65 to +150 | °C |
| Maximum storage temperature range | T _{Stg} | | -65 to +175 | U |
| Maximum thermal resistance, junction to case per leg | R _{thJC} | DC operation | 1.5 | |
| Typical thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth and greased (Only for TO-220) | 0.50 | °C/W |
| Maximum thermal resistance, junction to ambient | R _{thJA} | DC operation (For D ² PAK and TO-262) | 50 | |
| Approving to weight | | | 2 | g |
| Approximate weight | | | 0.07 | oz. |
| Mounting torgue | | Non-lubricated threads | 6 (5) | kgf · cm |
| Mounting torque maximum | | Non-Iubricated trireads | 12 (10) | (lbf · in) |
| Marking davias | | Case style D ² PAK | MBRB4 | 045CT |
| Marking device | | Case style TO-262 | MBR40 | 45CT-1 |

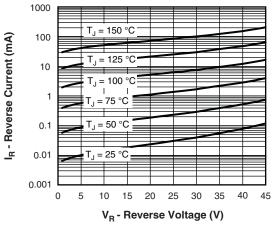


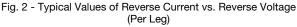
VS-MBRB4045CTPbF, VS-MBR4045CT-1PbF

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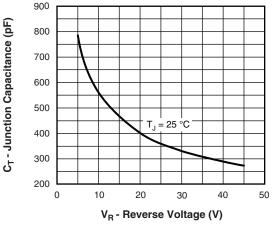


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

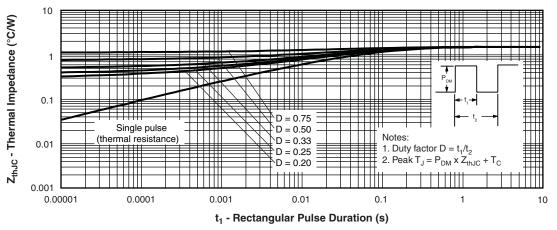
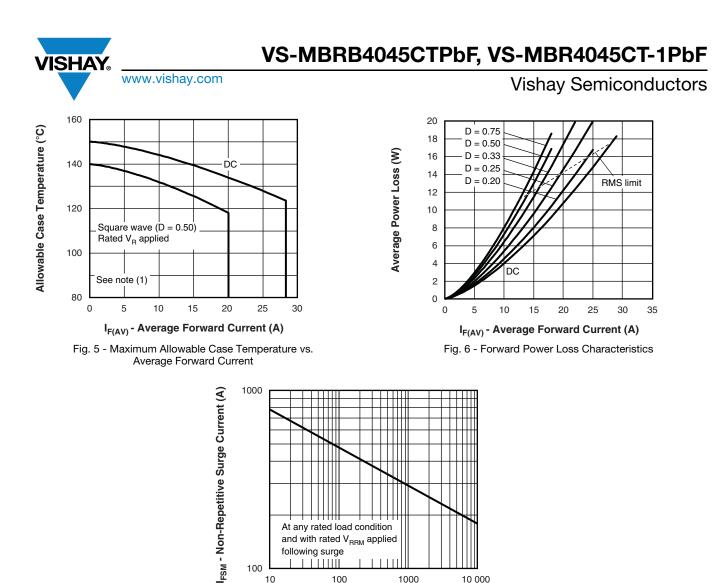
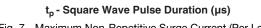


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

Revision: 15-Jul-14

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1000

10 000

following surge 1 | | | | | |

100

100

10

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = rated V_R$



VS-MBRB4045CTPbF, VS-MBR4045CT-1PbF

Vishay Semiconductors

ORDERING INFORMATION TABLE

| Device code | VS- | MBR | В | 40 | 45 | СТ | -1 | TRL | PbF |
|-------------|---------------------------------|---|---|--|--|---------------------|----------------------------------|---|-------|
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 |
| | 1 2 3 4 5 6 7 | - Ess - • B • N - Cur - Voli - CT - • N | ential pa = D ² PA one = T rent rati tage rati | O-262 [ng (40 = ng (45 = tial part ² PAK [| 7 Not 7 = - 40 A) 45 V) | ne 1 r | | | |
| | 8 | | | ibe (50 p | , | | | | |
| | 9 | • TI - • Pi | RR = tap bF = lea | e and re be and r d (Pb)-f Pb)-free | eel (righ ree (for | nt orient TO-262 | ed - for 2 and D ² | D ² PAK ² PAK tu | only) |

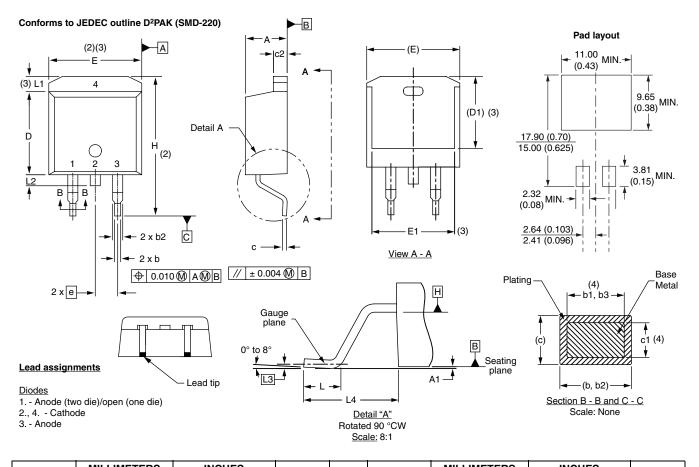
| LINKS TO RELAT | ED DOCUMENTS |
|--------------------------|--------------------------|
| Dimensions | www.vishay.com/doc?95014 |
| Part marking information | www.vishay.com/doc?95008 |
| Packaging information | www.vishay.com/doc?95032 |
| SPICE model | www.vishay.com/doc?95296 |

Vishay High Power Products

D²PAK, TO-262

DIMENSIONS FOR D²PAK in millimeters and inches

SHA



| SYMBOL | MILLIM | ETERS | INCHES | | NOTES |
|--------|--------|-------|--------|-------|-------|
| STMBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| A | 4.06 | 4.83 | 0.160 | 0.190 | |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.38 | 0.74 | 0.015 | 0.029 | |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 |

| SYMBOL | MILLIMETERS | | INC | HES | NOTES |
|--------|-------------|-------|-------|-------|-------|
| STMBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| е | 2.54 | BSC | 0.100 | BSC | |
| Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| L | 1.78 | 2.79 | 0.070 | 0.110 | |
| L1 | - | 1.65 | - | 0.066 | 3 |
| L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| L3 | 0.25 | BSC | 0.010 | BSC | |
| L4 | 4.78 | 5.28 | 0.188 | 0.208 | |
| | | | | | |

⁽⁷⁾ Outline conforms to JEDEC outline TO-263AB

Notes

- ⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only
- ⁽⁵⁾ Datum A and B to be determined at datum plane H
- ⁽⁶⁾ Controlling dimension: inch

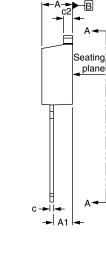
Vishay High Power Products

D²PAK, TO-262



DIMENSIONS FOR TO-262 in millimeters and inches







Lead tip



| OVMDOL | MILLIM | IETERS | INCHES | | NOTEO |
|----------|--------|----------|--------|-------|-------|
| SYMBOL - | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.06 | 4.83 | 0.160 | 0.190 | |
| A1 | 2.03 | 3.02 | 0.080 | 0.119 | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.38 | 0.74 | 0.015 | 0.029 | |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 |
| D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| е | 2.54 | 2.54 BSC | | BSC | |
| L | 13.46 | 14.10 | 0.530 | 0.555 | |
| L1 | - | 1.65 | - | 0.065 | 3 |
| L2 | 3.56 | 3.71 | 0.140 | 0.146 | |

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- ⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

⁽⁶⁾ Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

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